



## Features

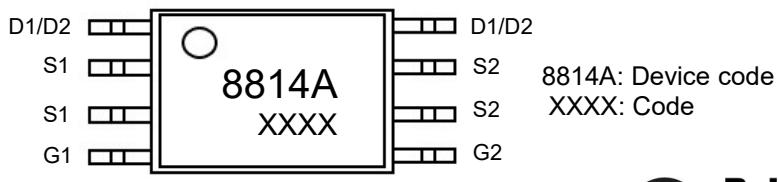
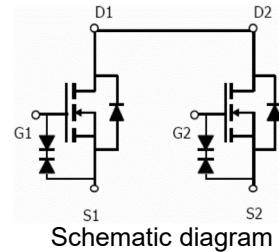
- High power and current handing capability
- Lead free product is acquired
- Surface mount package
- ESD protected

## Application

- Battery protection
- Load switch
- Power management

## Product Summary

V <sub>DS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX
20V	16mΩ@10V	7.5A
	18mΩ@4.5V	



8814A: Device code  
XXXX: Code

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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## Common Ratings (TC=25°C Unless Otherwise Noted)

V <sub>DS</sub>	Drain-Source Breakdown Voltage	20	V
V <sub>GS</sub>	Gate-Source Voltage	±12	V
T <sub>J</sub>	Maximum Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C
I <sub>S</sub>	Diode Continuous Forward Current	Tc=25°C 7.5	A

## Mounted on Large Heat Sink

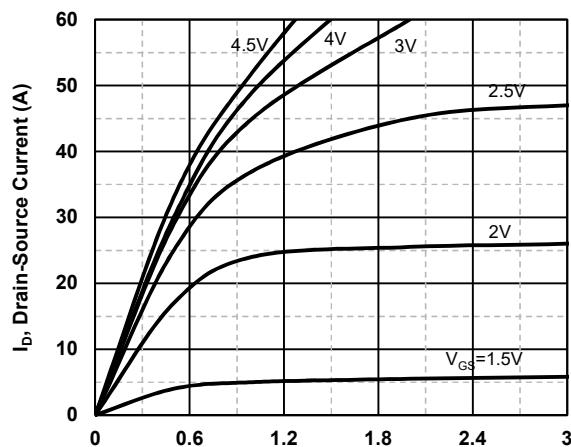
I <sub>DM</sub>	Pulse Drain Current Tested	Tc=25°C 32	A
I <sub>D</sub>	Continuous Drain Current	Tc=25°C 7.5	A
P <sub>D</sub>	Maximum Power Dissipation	Tc=25°C 1.5	W
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient	120	°C/W

## Ordering Information (Example)

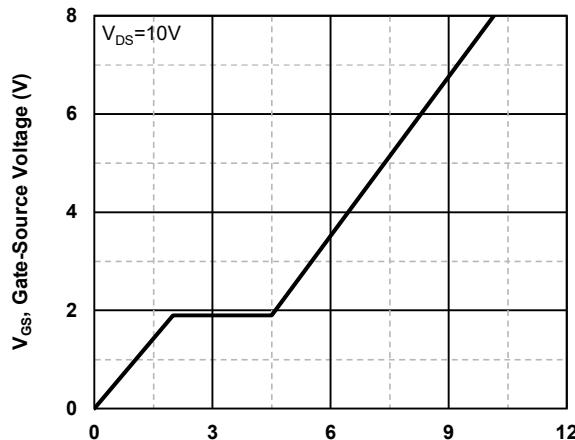
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLSS8814A	TSSOP-8	8814A	3,000	6,000	42,000	13" reel

<b>Electrical Characteristics (TJ=25°C unless otherwise noted)</b>						
<b>Symbol</b>	<b>Parameter</b>	<b>Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
<b>Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	20	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	--	--	±10	μA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.5	0.7	1.0	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =7.5A	--	13	16	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =7.0A	--	15	18	mΩ
		V <sub>GS</sub> =3.6V, I <sub>D</sub> =6.0A	--	16.8	20	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =6.0A	--	19	24	mΩ
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =5.0A	--	26	34	mΩ
<b>Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz	--	630	--	pF
C <sub>OSS</sub>	Output Capacitance		--	135	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	116	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =10V, I <sub>D</sub> =7.5A, V <sub>GS</sub> =10V	--	12	--	nC
Q <sub>qs</sub>	Gate Source Charge		--	2	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	2.5	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =10V, I <sub>D</sub> =7.5A, V <sub>GS</sub> =10V, R <sub>GEN</sub> =2.2Ω	--	4	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	15	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	18	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	8	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =7.5A	--	--	1.0	V

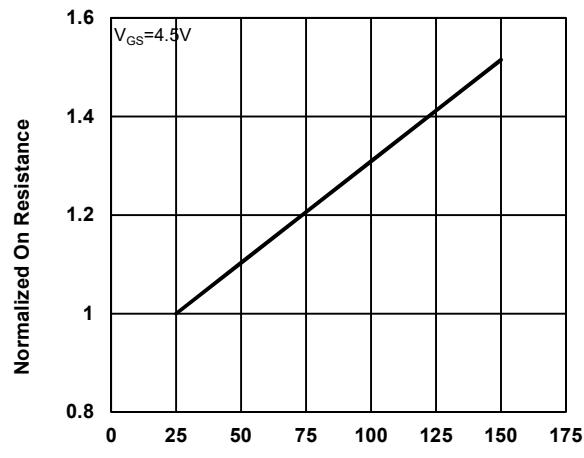
### Typical Operating Characteristics



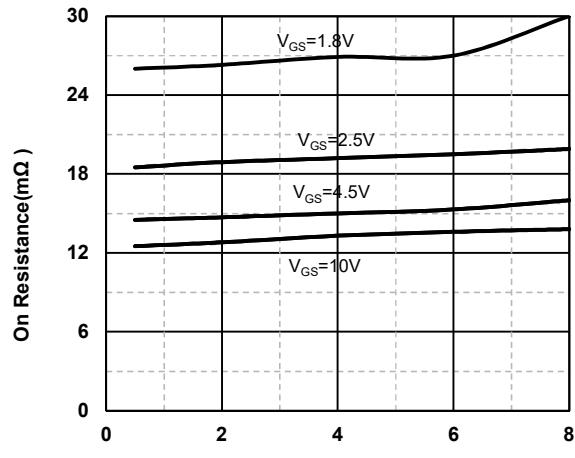
$V_{DS}$ , Drain -Source Voltage (V)  
 Fig1. Typical Output Characteristics



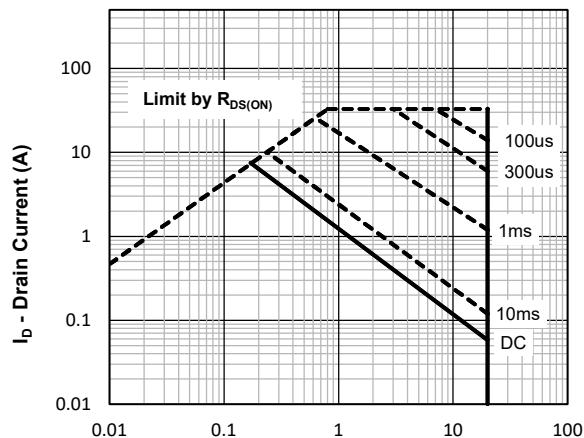
$Q_g$  -Total Gate Charge (nC)  
 Fig2. Typical Gate Charge Vs.Gate-Source Voltage



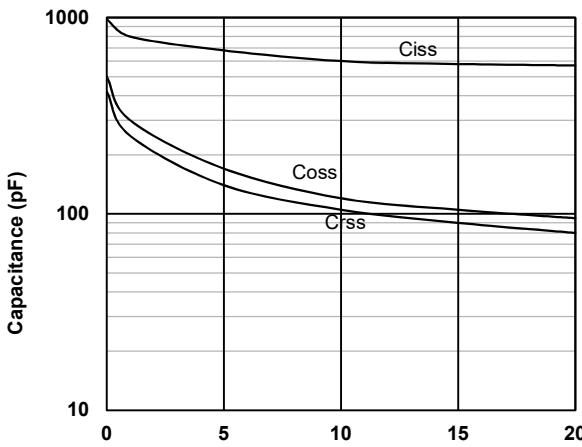
$T_j$  - Junction Temperature (°C)  
 Fig3. Normalized On-Resistance Vs. Temperature



$I_D$ , Drain-Source Current (A)  
 Fig4. On-Resistance Vs. Drain-Source Current



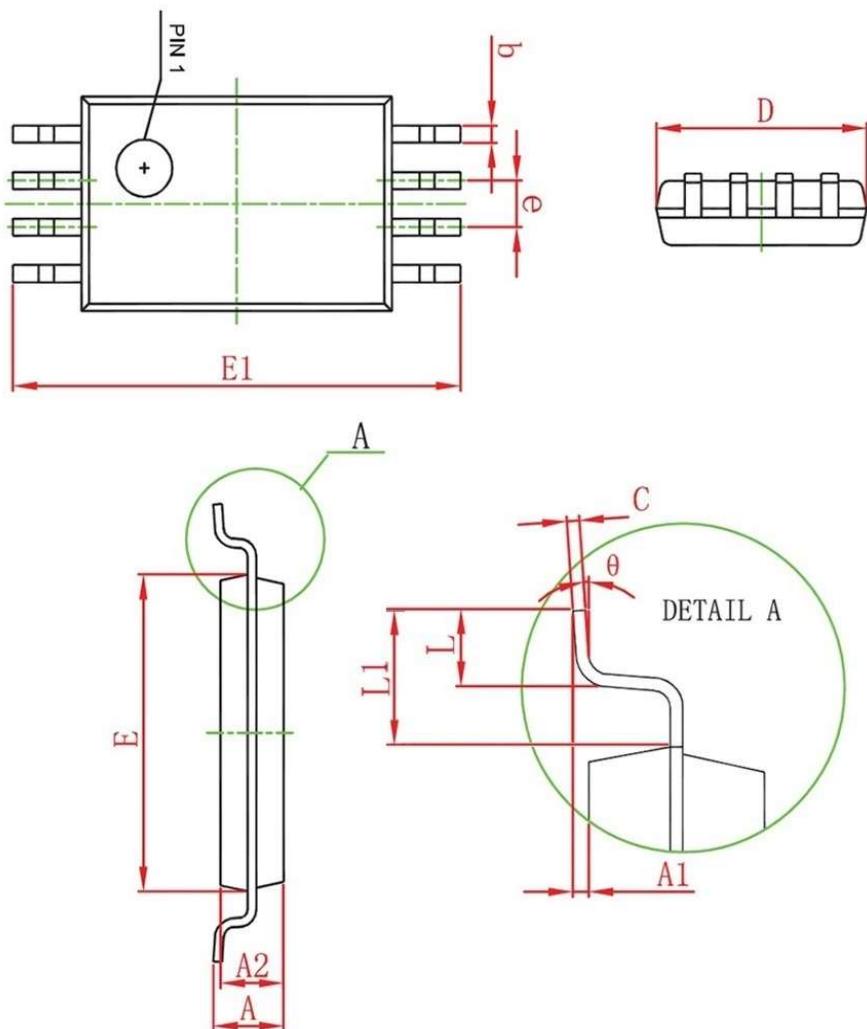
$V_{DS}$ , Drain -Source Voltage (V)  
 Fig5. Maximum Safe Operating Area



$V_{DS}$ , Drain-Source Voltage (V)  
 Fig6 Typical Capacitance Vs.Drain-Source Voltage



**TSSOP-8 Package information**



Symbol	Dimensions in Millimeters(mm)		Dimensions in Inches	
	Min	Max	Min	Max
A	1.000	1.200	0.039	0.047
A1	0.020	0.180	0.000	0.007
A2	0.900	1.100	0.035	0.043
b	0.170	0.270	0.006	0.010
c	0.122	0.132	0.004	0.005
D	2.870	3.070	0.112	0.120
e	0.65BSC		0.025BSC	
E	4.300	4.500	0.169	0.177
E1	6.200	6.600	0.244	0.259
L	0.400	0.800	0.015	0.031
L1	1.00BSC		0.039BSC	
Ø1	0.500	0.700	0.001	0.027
θ	0°	10°	0°	10°